

## SKD 146/.. - L100

$V_{RSM}$ V	$V_{RRM}$ V	$I_{RMS}$ (maximum values for continuous operation) ( $T_h = 80^\circ C$ ) 140 A
1300	1200	<b>SKD 146/12-L100</b>
1700	1600	<b>SKD 146/16-L100</b>

Symbol	Conditions <sup>1)</sup>	Values	Units
Bridge Rectifier			
$I_D$	$T_{heatsink} = 85^\circ C$ ; inductive load	140	A
$I_{FSM}/I_{TSM}$	$t_p = 10 \text{ ms}; \sin. 180^\circ C, T_{jmax}$	1250	A
$I^2t$	$t_p = 10 \text{ ms}, \sin. 180^\circ, T_{jmax}$	7800	A <sup>2</sup> s
IGBT Chopper			
$V_{CES}$	$T_{heatsink} = 25 / 70^\circ C$	1200	V
$V_{GES}$		$\pm 20$	V
$I_C$	$T_{heatsink} = 25 / 70^\circ C$	125 / 100	A
$I_{CM}$	$t_p = 1 \text{ ms}; T_{heatsink} = 25 / 70^\circ C$	250 / 200	A
Freewheeling Diode <sup>2)</sup>			
$V_{RRM}$	$T_{heatsink} = 25 / 70^\circ C$	1200	V
$I_F$	$t_p = 1 \text{ ms}; T_{heatsink} = 25 / 70^\circ C$	130 / 90	A
$I_{FM}$		240 / 180	A
$T_j$	Diode & IGBT	-40 ... +150	°C
$T_j$	Thyristor	-40 ... +125	°C
$T_{stg}$		-40 ... +125	°C
$V_{isol}$	AC, 1 min.	2500	V

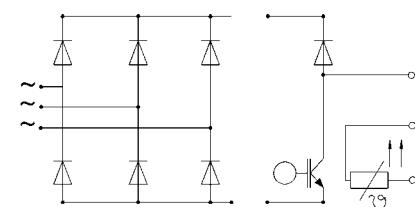
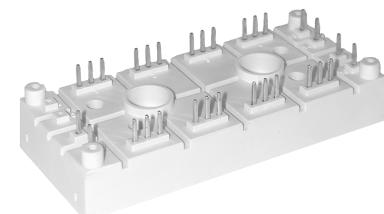
Symbol	Conditions <sup>1)</sup>	min.	typ.	max.	Units
Diode - Rectifier					
$V_F$	$I_F = 150 \text{ A} \quad T_j = 125^\circ C$	-	1,3	-	V
$V_{TO}$	$T_j = 125^\circ C$	-	0,8	-	V
$r_T$	$T_j = 125^\circ C$	-	4	-	mΩ
$R_{thjh}$	per diode	-	0,6	-	K/W
IGBT - Chopper					
$V_{CEsat}$	$I_C = 100 \text{ A} \quad T_j = 25^\circ C, V_{GE} = 15 \text{ V}$	-	2,35	2,85	V
$t_{d(on)}$	$V_{CC} = 600 \text{ V}; V_{GE} = \pm 15 \text{ V}$	-	70	-	ns
$t_r$	$I_C = 100 \text{ A}; T_j = 125^\circ C$	-	50	-	ns
$t_{d(off)}$	$R_{gon} = R_{goff} = 7 \Omega$	-	450	-	ns
$t_f$	inductive load	-	45	-	ns
$E_{on} + E_{off}$		-	25	-	mJ
$C_{ies}$	$V_{CE} = 25 \text{ V}; V_{GE} = 0 \text{ V}, f = 1 \text{ MHz}$	-	7,7	-	nF
$R_{thjh}$	per IGBT	-	-	0,28	K/W
Diode <sup>2)</sup> - Freewheeling					
$V_F$	$I_F = 100 \text{ A} \quad T_j = 25^\circ C$	-	2,0	2,5	V
$V_{TO}$	$T_j = 125^\circ C$	-	1,1	1,2	V
$r_T$	$T_j = 125^\circ C$	-	-	11	mΩ
$I_{RRM}$	$I_F = 100 \text{ A}; V_R = -600 \text{ V}$	-	65	-	A
$Q_{rr}$	$dI_F/dt = -1000 \text{ A}/\mu\text{s}$	-	15	-	μC
$E_{off}$	$V_{GE} = 0 \text{ V}, T_j = 125^\circ C$	-	TBD	-	mJ
$R_{thjh}$	per diode	-	-	0,56	K/W
Temperature Sensor					
$R_{TS}$	$T = 25 / 100^\circ C$	1000 / 1670		$\Omega$	
Mechanical Data					
$M_1$ Case	case to heatsink, SI Units	2,5	-	3,5	Nm
			G 60		

## SEMIPONT™ 6

### SKD 146/.. - L100

#### 3-phase bridge rectifier + IGBT braking chopper

##### Preliminary Data



- Specifications of temperature sensor see part A

##### Features

- Compact design
- Two screws mounting
- Heat transfer and isolation through direct copper board (low  $R_{th}$ )
- Low resistance in steady-state and high reliability
- High surge currents
- Up to 1600 V reverse voltage
- UL recognized, file no. E 63 532

##### Typical Applications

- DC drives
- Controlled field rectifiers for DC motors
- Controlled battery charger

<sup>1)</sup>  $T_{heatsink} = 25^\circ C$ , unless otherwise specified

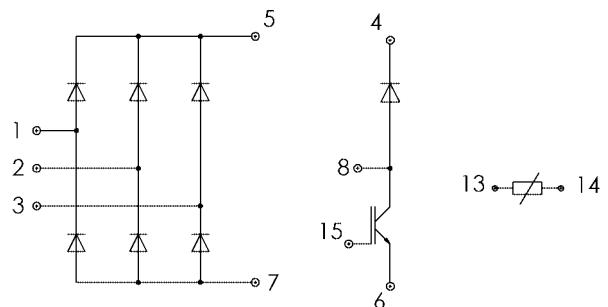
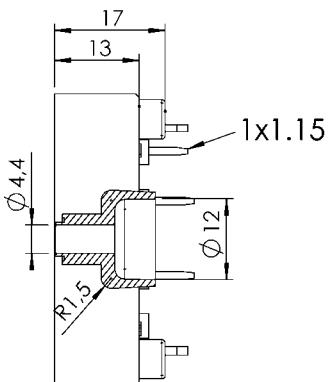
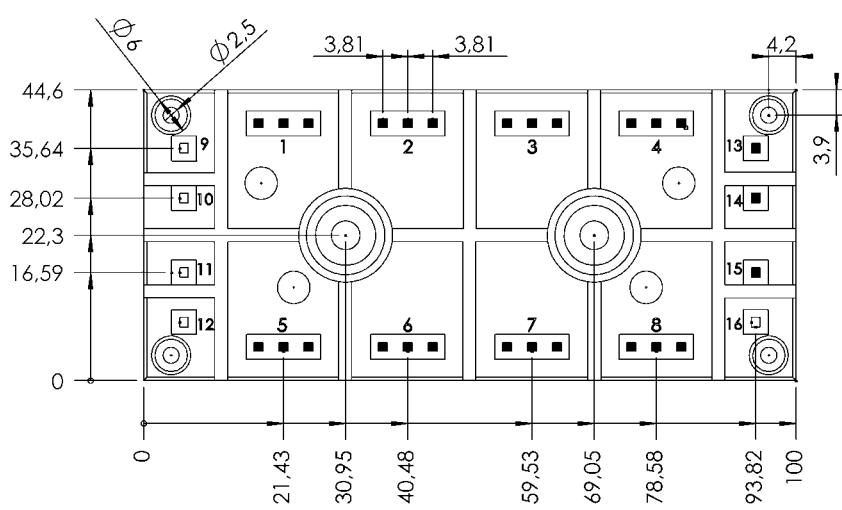
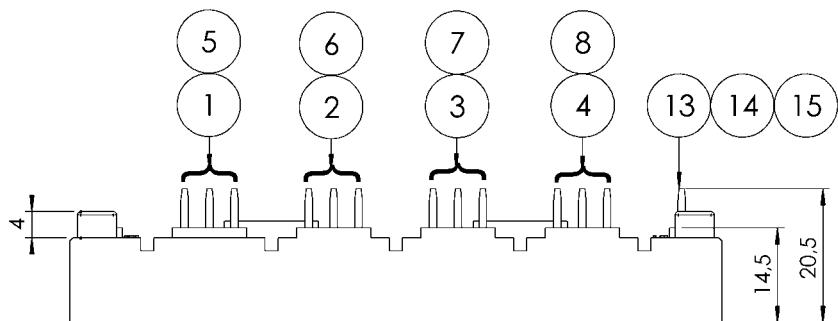
<sup>2)</sup> CAL = Controlled Axial Lifetime Technology (soft and fast recovery)

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Case G 60



Dimensions in mm

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